# Spin B lockade in Single and D ouble Q uantum D ots in M agnetic Fields: a C orrelation E ect 

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#### Abstract

The totalspin of correlated electrons in a quantum dot changes $w$ ith $m$ agnetic eld and this e ect is generally linked to the change in the totalangularm om entum from onem agic num ber to another, which can be understood in term sof an electron molecule' picture for strong elds. H ere we propose to exploit th is fact to realize a spin blockade, i.e., electrons are prohibited to tunnelat speci c values of the $m$ agnetic eld. The spin-blockade regions have been obtained by calculating both the ground and excited states. In double dots the spin-blockade condition is found to be less stringent than in single dots.


T he C oulom b blockade is one of the highlights in the transport properties ofm esoscopic system $s$ such as quantum dots. This is a com bined e ect of the discreteness of energy levels and the electron-electron interaction (charging energy). Now, it has recently been suggested that, if the total spins of the ground state of $N$ and $(\mathbb{N} 1$ )electrons di er by $m$ ore than $1 / 2$, the dot is blocked with the corresponding peak in the conductance $m$ issing at zero tem perature. This is called the spin-blockade [ and has been studied theoretically for weak electron interaction regim es. There the H und's coupling picture, in $w$ hich electrons are accom $m$ odated in one-electron states w ith high spins for degenerate states, tends not to realize the spin-blockade condition, so that som emodi cations such as an anham onicity in the con nem ent potential [1] have to be introduced.

W hen quantum dots are placed in strong $m$ agnetic elds, the ground states are know $n$ to change dram atically into them agic-num ber states [ [4] the electron correlation e ect, since the $m$ agic num bers for the total angular $m$ om entum arise from a combined e ect of the electron correlation and Pauli's principle, persisting even when the Zeem an energy is com pletely ignored. The total angular $m$ om entum of the ground state jumps from one $m$ agic number to another as the m agnetic eld B is varied.

An im portant hint that electron correlation is really at work is the fact that the total spin (S), where $S^{2}=$ $S(S+1)$, of the ground state, which dom inates how the electrons correlate, changes w ildly as shown in $F$ ig. ${ }_{1}^{11}$. $T$ his happens when the typical C oulom b energy is $m$ uch greater than the single-electron levelspacing, where electron $m$ olecule are form ed. In this sense this is genuinely an electron-correlation e ect | electron correlation has been known to dom inate the spin states in ordinary correlated electron system s such as the H ubbard m odel, but the present case is a peculiar $m$ anifestation in strong m agnetic elds.

In the present paper we propose to utilize this elec-
tron correlation e ect to realize a spin blockade. W e have num erically studied the ground and excited states of single dots that contain three or four electrons with a parabolic con nem ent potential and nd that the spin blockade should indeed be observed. P hysically, a key observation starts from the fact that the correlated electron states in the dot $m$ ay be thought of as electron m olecules $\left.{ }^{\prime}[\underline{[ }]\right]$, which in tum enables us to intenpret [ $\overline{1}_{1}$ ] the spin wavefiunctions taking part in the spin blockade as spin con gurations in molecules, which include the resonating valence bond (RVB) states, that are usually invoked for lattice ferm ions. We further show that the spin-blockade condition is easier to satisfy in double dots which can be tuned by controlling the layer separation and the strength of the interlayer tunneling.

So let us start w ith looking at the total angular mo$m$ entum ( $L$ ) of 2D electrons con ned in a quantum dot in a magnetic eld, which has a pne-to-one correspondence w ith the spatial extent (/ $\bar{L}$ ) of the w avefunction. T hus the presence of $m$ agic $L$ values signi es that the total C oulom bic energy of the interacting electrons, although roughly a decreasing function of $L$ as the electrons $m$ ove further apart for larger $L$, is not a sm ooth function of the size of the w avefunction, so that jum ps in L are accom panied by jum ps in the size of the w ave function $\left[\frac{8}{1} \bar{q}_{1}^{9}\right]$. For exam ple, the totalangularm om entum L of three spin-polarized electrons changes $3!6!9!:::$ $w$ ith increasing $m$ agnetic eld.

Recently one of the authors has explained this as an e ect of correlation in the electron con guration, where Pauli's exclusion principle dictates group-theoretically the $m$ anner in which the quantum numbers should appear $[\underline{[ }]]$. There, the picture of the electron molecule', in which the electrons with a speci c con guration (triangle for three electrons, square for four, etc) rotating as a whole has tumed out to be surprisingly accurate. $T$ his continues to be the case for larger num bers of electrons [1]d].

W hen one considers the spin degrees of freedom, the
$m$ agic $L$ values are linked $w$ ith the total spin. This is already apparent in the rst num erical study of spin dependent correlation in quantum dots $\left[\overline{1}_{1}^{1}\right]$. These $m$ olecules are characterized by a quantum number, $\mathrm{k}_{\mathrm{s}}$, where the spin wave function spin is transform ed to $\exp \left(2 k_{s} i=m\right)$ spin under the rotation of $2=m$ for an $m$ fold sym $m$ etric $m$ olecule. $T$ hen the criterion for the $m$ agic num ber, $m$ odulo $m$, reads $L+k_{s} \quad 0(m=2)$ for $m$ odd (even).

To actually obtain the spin states num erically for different num bers of electrons, let us consider single G aA s quantum dots w ith three or four electrons in a parabolic potential. The electron $m$ otion is assum ed to be completely two dim ensional. The Ham iltonian for a single dot is $\mathrm{H}=\mathrm{H}_{\mathrm{s}}+\mathrm{H}_{\mathrm{C}}$, where

$$
H_{s}=\begin{array}{lll}
X & X & X  \tag{1}\\
n
\end{array} \quad \#_{n}, C_{n}^{y}, C_{n}, ;
$$

is the single-electron part, while
represents the C oulomb interaction. H ere the H am iltonian is written in second quantized form in a Fock-
 $\left.!{ }_{0}^{2}\right)^{1=2} \quad ` h!{ }_{\mathrm{C}}=2 \quad \mathrm{~g} \quad \mathrm{~B}$ B $S_{\mathrm{z}}$. The dielectric constant is, $h!o$ represents the strength of the parabolic con nem ent potential, $!_{c}=e B=m \quad c$ is the cyclotron frequency, $m$ is the e ective $m$ ass, $B$ is the Bohrm agneton, $g$ is the e ective g-factor and $s_{z}$ is $z$-com ponent of the spin of a single electron.

W e use the con nem ent potentialh ${ }_{0}=6: 0 \mathrm{meV}$. Th is is a little larger than usually estim ated values (2 4 meV ) and is deliberately chosen to reproduce the addition energy spectrum [13]. The fact that calculations w th a $1=\mathrm{r}$ interaction require a larger con nem ent energy to reproduce experim ental results is considered to be a consequence of the $m$ odi cation of the interaction potential in real dots $\left.{ }_{11}^{1} 4_{1}^{\prime}\right]$.

In our num erical calculations we have used enough states (including higher Landau levels) in the basis to ensure convergence of the ground-state energy w ithin $0: 1 \%$. T hree low est excited states are also calculated for each value ofB, which tum out to be the low est-energy states having di erent angular $m$ om enta in the present case. Excited states are also obtained w ith a typical accuracy of $<0: 1 \%$ for an $N=3$ single dot at $B=5 \mathrm{~T}$.

The total angular $m$ om entum, and the total spin of the ground state for three- and four-electron system s plotted in Fig. ${ }_{1} 11$, we can see how the magic $L$ values go hand in hand with $S(\mathbb{N})$ for $N$ electrons, where $S^{2}=S(S+1)$ while the $z$ com ponent of $S$ is aligned
to $B$ : As the $m$ agnetic eld increase, the ground state changes as $(L ; S)=(1 ; 1=2)!(2 ; 1=2)!(3 ; 3=2)$ for $\mathrm{N}=3,(\mathrm{~L} ; \mathrm{S})=(0 ; 1)!(2 ; 0)!(3 ; 1)!(4 ; 0)!$ $(5 ; 1)!(6 ; 2)$ for $N=4$.

If we then plot the di erence in the total spin, $S$ (4) $S$ (3), against the $m$ agnetic eld in the bottom panel of Fig.

$$
\begin{equation*}
j(\mathbb{N}) \quad S(\mathbb{N} \quad 1) j>\frac{1}{2} \tag{3}
\end{equation*}
$$

is indeed full led: S jumps from 3/2 to 0 in the region $4: 96<B<5: 18 \mathrm{~T}$.

From the $m$ agic-num ber criterion the state $w$ ith ( $L=$ $2+4$ integer) has to have the quantum num ber $\mathrm{k}_{\mathrm{s}}=0$, while the ( $L=4$ integer) state $k_{s}=2$ for $N=4 . W e$ can $m$ ake an intriguing identi cation, by looking at the spin density correlation function, that $(L ; S)=(2 ; 0)$ is an RVB state while $(4 ; 0)$ is an RVB ${ }^{+}$, where the RVB's are de ned, for a four-site cluster, as

$$
\begin{align*}
& \text { RVB : } \quad-\boxed{\square} \tag{4}
\end{align*}
$$

$$
\begin{align*}
& \mathrm{RVB}^{+}: \square+\square \equiv \mathbb{Z} \tag{5}
\end{align*}
$$

with $\int \frac{1}{\overline{2}}(j$ "\#i $j \#$ "i) being the spin-singlet pair in the electron molecule. The di erence of RVB ${ }^{+}$ from RVB is that the form er lacks the $N$ eelcom ponents (the last two term $s$ in RVB ) and has the extra phase factor -1 for $=2$ rotation. A though what we have here is totally di erent from lattice ferm ion system $s$ such as the $H$ ubbard $m$ odel for which RVB is usually concived, the electron-m olecule form ation has brought about such spin con gurations.


FIG.1. The total angular $m$ om entum and total spin of the ground state for a single quantum dot with $\mathrm{N}=3$ (left) or $\mathrm{N}=4$ electrons (right). The con nem ent potential is assum ed to be parabolic w ith $\mathrm{h}!0=6: 0 \mathrm{~m} \mathrm{eV}$.

In this region, the conduction, blocked at zero tem perature, has to occur through an $S=1$ excited state for $\mathrm{N}=4$ at nite tem peratures. If the excited states are well separated in energy ( 0.1 m eV , typical experim ental resolution for C oulom b diam onds) from the ground state for both of the $(\mathbb{N}$ 1) electron and $N$ electron states, the spin blockade should be observed in the C oulom b diam ond, which is the di erential conductance plotted in the plane of source-drain voltage and gate voltage. W e have calculated the three low est excitation energies and their total spins for the $N=4$ quantum dot in $F$ ig. $\overline{1}$, 1 . The low est excited states for $N=3$ and for $\mathrm{N}=4$ both lie about 0.06 m eV above the ground state around $B=5: 1 \mathrm{~T}$ in the spin-blockade region. W e can m ake th is separation larger ( 0.1 m eV ) for stronger connem ent potentials (e.g., 0.09 m eV around $B=7: 4 \mathrm{~T}$ for $h!0=8: 0 \mathrm{meV})$. Such con nem ent potentials $m$ ay be realized in a gated verticalquantum dot [13'].
$T$ he link betw een the $m$ agic $L$ and total $S$ and subsequent spin blockade appears for other num bers of electrons as well, e.g., betw een $(L ; S)=(2 ; 0)$ state for $N=2$ and $(6 ; 3=2)$ state for $N=3$ for $14: 1<B<14: 8 \mathrm{~T}$.


FIG.2. Top: Excitation energies for $N=4$ single dot. M iddle: T he sam f for $\mathrm{N}=3$. B ottom : D i erence in the total spin, $S(4) \quad S(3)$, betw een the ground state for $N=3 ; 4)$.

N ow we m ove on to the double dots, where dots are separated in the vertical direction $w$ ith their centers aligned on a com $m$ on axis. We assume the sam e connem ent potential for the two dots for sim plicity. H ere electrons are C oulom b-correlated both w ithin each layer and across the tw o layers, in the presence of the interlayer tunneling. Recent advances in sem iconductor fabrication techniques have enabled fabrication of double dots in vertical, triple-barrier structures on subm icron
scales [1] Th. Theory for the double quantum dots has been developed [1] \{2 12], where intriguing features such as m agic-num ber states intrinsic to double dots, or a singlet-to-triplet spin transition for tw o-electron system have been found [1] [1] $]$.

The H am iltonian now contains the tunneling tem,

$$
\begin{equation*}
H_{t}=\frac{S A S}{2}_{n}^{X}, \quad C_{n}^{y}, c_{n},+c_{n}^{y}, c_{n} \cdot+; \tag{6}
\end{equation*}
$$

while the Coulomb part is now the matrix elem ent of $e^{2}=j_{1} \quad r_{2} j$ for intra-layer interaction, and $e^{2}=\left(j_{1}\right.$ $\left.r_{2} \jmath+d^{2}\right)^{1=2}$ for inter-layer interaction. The basis is $\eta_{i}{ }_{i}{ }_{i}{ }_{i} i$, where $=$ is an index specifying the two dots.

Thus a double dot is characterized by the parabolic con nem ent potential layer, $h!0$, the layer separation, $d$, and the strength of the inter-layer tunneling ( $m$ easured by SA s, the energy gap betw een the sym $m$ etric and antisym $m$ etric one-electron states). H ere we have adopted realistic values of $\mathrm{h}!0=6: 0 \mathrm{meV}, 10 \mathrm{~d} \quad 50 \mathrm{~nm}, 02$

SAs $\quad 2.0 \mathrm{meV}$. W e can now plot in $F$ ig. spin states appear on the SAS d plane. A high-spin state is indeed seen to appear in the upper left region of each panel for $B=5: 0 \mathrm{~T}$. In the shaded region of the right panel, the di erence betw een the total spins is $S$ (3) $S(2)=3=2$, fiul lling the spin blockade condition.


FIG.3. The ground-state spin of the double dot for $\mathrm{N}=2$ (left) or $\mathrm{N}=3$ (right) for $\mathrm{B}=5 \mathrm{~T}$ for a parabolic con nem ent potential $\mathrm{h}!0=6: 0 \mathrm{meV}$. Shaded region corresponds to a transition from $S=0!3=2$

W e now focus on a typical point in the shaded region, $d=16: 0 \mathrm{~nm}$ and $\mathrm{SAs}=1: 2 \mathrm{meV}$. In F ig. $\mathrm{I}_{1}^{1 / 1}$ the total energy, total angular $m$ om entum and the total spin of the ground state for $N=2 ; 3$ are plotted.
$T$ he di erence betw een the total spin of tw o and three electrons system $s$ is shown in the bottom panelofF ig. The spin-blockade condition is satis ed for 4.0 B $9: 3 \mathrm{~T}$, which is wider than for the single dot. In the bulk bilayer fractional quantum H all ( Q H ) system s , a phase diagram on the SAS d plane has been considered. If
we translate $\left[\bar{Z}_{1}\right]$ the quantities for the dots, we are w orking in the two-com ponent' (correlation-dom inated) region around the QH -non QH boundary in the language for the bilayer $\mathrm{Q} H$ system. This m ight have som e relevance to the behavior of the double dots. In $F$ ig. ${ }^{1} \overline{1}_{1}$, the excitation energies for the $S=1=2 ; 3=2$ states are also plotted. The excitation energies for both $\mathrm{N}=2$ and $\mathrm{N}=3$ system s are about 0.12 m eV (exceed 0.1 meV ) at $B=6: 4 \mathrm{~T}$, which is large enough for the spin blockade to be observed. W e also notice a level crossing betw een the second and the third excited states around $B=6: 9 \mathrm{~T}$ for $\mathrm{N}=3$, which should appear in the C oulom b diam ond.


FIG.4. The totalangularm om entum and totalspin of the ground state for double dots w th $\mathrm{N}=2$ (left) $\mathrm{N}=3$ (right) electrons. $\mathrm{h}!_{0}=6: 0 \mathrm{~m} \mathrm{eV} . d=16: 0 \mathrm{~nm}$, and $\mathrm{sAs}=1: 2$ meV .


FIG.5. Top (middle): Excitation energies for $N=3$ $(\mathbb{N}=2)$ double dots. B ottom : The di erence, $S(3) \quad S(2)$, in the total spin for $\mathrm{N}=2$ and $\mathrm{N}=3$ double dots.

In sum $m$ ary, we have show $n$ that in both single and double dots, a spin blockade should occur in som e m agnetic eld region, as an e ect of the totalspin dom inated by the $m$ agic angular mom enta. W e would like to thank to Seigo Tanucha and G uy A usting for a num ber of vahuable discussions.
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